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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

PESD3V3L1UA; PESD3V3L1UB; PESD3V3L1UL

Low capacitance unidirectional ESD protection diodes

Rev. 01 — 17 June 2009

Product data sheet

1. Product profile

1.1 General description

Low capacitance unidirectional ElectroStatic Discharge (ESD) protection diodes in small Surface-Mounted Device (SMD) plastic packages designed to protect one signal line from the damage caused by ESD and other transients.

Table 1. Product overview

Type number	Package		Package configuration
	NXP	JEITA	
PESD3V3L1UA	SOD323	SC-76	very small
PESD3V3L1UB	SOD523	SC-79	ultra small and flat lead
PESD3V3L1UL	SOD882	-	leadless ultra small

1.2 Features

- Unidirectional ESD protection of one line
- Low diode capacitance: C_d = 34 pF
- Low clamping voltage: V_{CL} = 11 V
- Very low leakage current: I_{RM} = 100 nA
- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- AEC-Q101 qualified

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Communication systems
- Subscriber Identity Module (SIM) card protection
- Portable electronics
- FireWire
- High-speed data lines

1.4 Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RWM}	reverse standoff voltage		-	-	3.3	V
C_d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	34	40	pF



Low capacitance unidirectional ESD protection diodes

Pinning information 2.

Table 3. **Pinning**

Pin	Description	Simplified outline	Graphic symbol
PESD3V3	L1UA; PESD3V3L1UB		
1	cathode	[1]	
2	anode	001aab540	1 2 006aaa152
PESD3V3	L1UL		
1	cathode	[1]	
2	anode	Transparent top view	1 2 006aaa152

^[1] The marking bar indicates the cathode.

Ordering information 3.

Table 4. **Ordering information**

Type number	Package		
	Name	Description	Version
PESD3V3L1UA	SC-76	plastic surface-mounted package; 2 leads	SOD323
PESD3V3L1UB	SC-79	plastic surface-mounted package; 2 leads	SOD523
PESD3V3L1UL	-	leadless ultra small plastic package; 2 terminals; body $1.0 \times 0.6 \times 0.5$ mm	SOD882

Marking

Table 5. **Marking codes**

Type number	Marking code
PESD3V3L1UA	1H
PESD3V3L1UB	Z7
PESD3V3L1UL	XW

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Product data sheet

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Limiting values 5.

Table 6. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{PP}	peak pulse power	$t_p = 8/20 \; \mu s$	[1][2]	45	W
I _{PP}	peak pulse current	$t_p = 8/20 \; \mu s$	[1][2]	4.5	Α
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

Table 7. **ESD** maximum ratings

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{ESD} electrostatic discharge voltage		IEC 61000-4-2 (contact discharge)	<u>[1]</u>	-	30	kV
	machine model		-	400	V	
		MIL-STD-883 (human body model)		-	10	kV

^[1] Device stressed with ten non-repetitive ESD pulses.

Table 8. **ESD** standards compliance

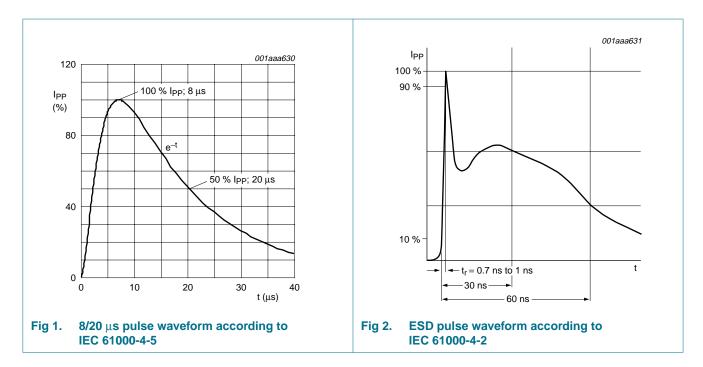
Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV

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^[2] Measured from pin 1 to pin 2.

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6. **Characteristics**

Table 9. **Characteristics**

T_{amb} = 25 °C unless otherwise specified.

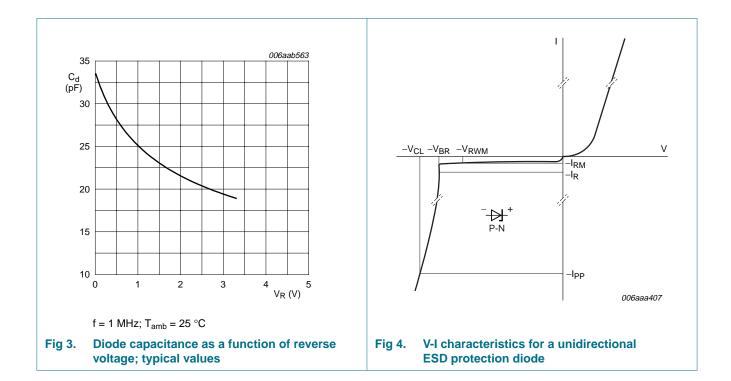
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RWM}	reverse standoff voltage		-	-	3.3	V
I _{RM}	reverse leakage current	$V_{RWM} = 3.3 V$	-	100	300	nA
V_{BR}	breakdown voltage	$I_R = 5 \text{ mA}$	5.3	5.6	6.0	V
C _d	diode capacitance	f = 1 MHz; $V_R = 0 V$	-	34	40	pF
V_{CL}	clamping voltage		[1][2]			
		$I_{PP} = 1 A$	-	-	8	V
		$I_{PP} = 4.5 A$	-	-	11	V
r _{dif}	differential resistance	$I_R = 5 \text{ mA}$	-	-	30	Ω
V_{F}	forward voltage	$I_F = 200 \text{ mA}$	-	-	1.2	V

^[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

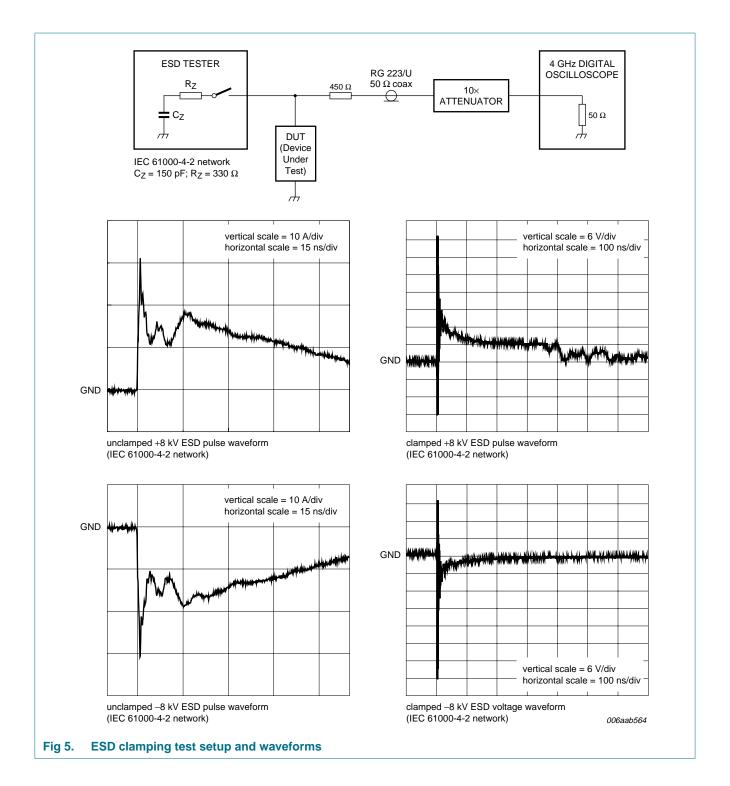
^[2] Measured from pin 1 to pin 2.

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Low capacitance unidirectional ESD protection diodes

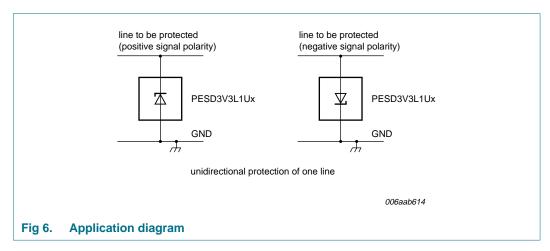


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Low capacitance unidirectional ESD protection diodes

7. Application information

The PESD3V3L1Ux series is designed for the protection of one unidirectional data or signal line from the damage caused by ESD and surge pulses. The devices may be used on lines where the signal polarities are either positive or negative with respect to ground. The PESD3V3L1Ux series provides a surge capability up to 45 W per line for an 8/20 μ s waveform.



Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD and Electrical Fast Transient (EFT). The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. The path length between the device and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

8. Test information

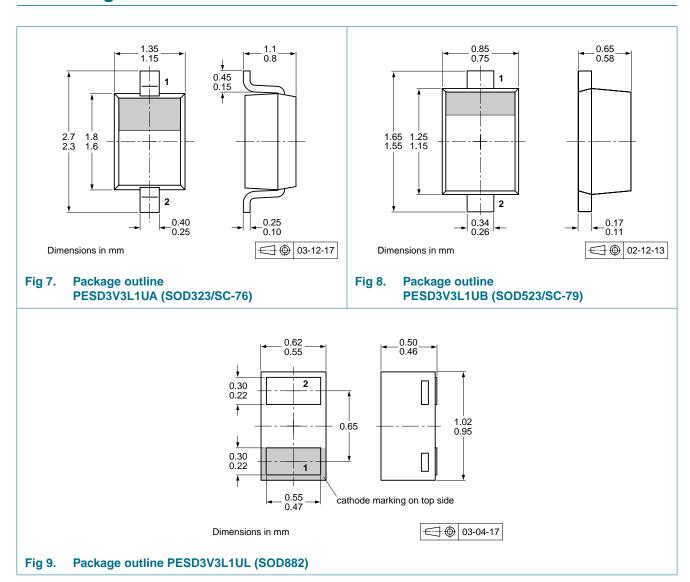
8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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Low capacitance unidirectional ESD protection diodes

Package outline



10. Packing information

Product data sheet

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Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packin	g quanti	ty
			3000	8000	10000
PESD3V3L1UA	SOD323	4 mm pitch, 8 mm tape and reel	-115	-	-135
PESD3V3L1UB SOD523		2 mm pitch, 8 mm tape and reel	-	-315	-
		4 mm pitch, 8 mm tape and reel	-115	-	-135
PESD3V3L1UL	SOD882	2 mm pitch, 8 mm tape and reel	-	-	-315

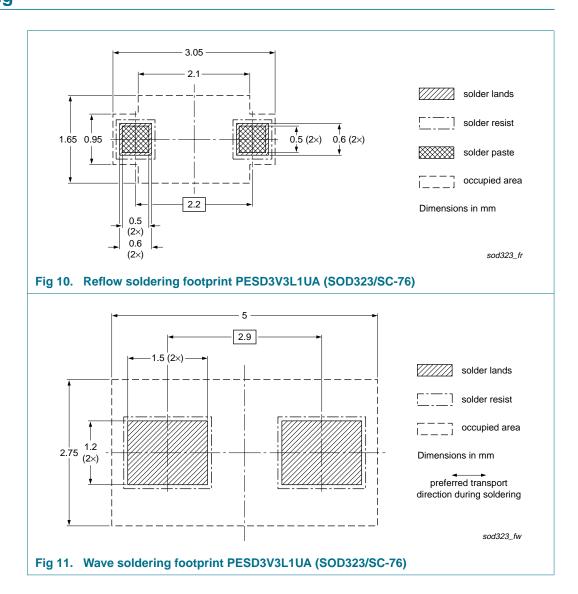
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[1] For further information and the availability of packing methods, see Section 14.

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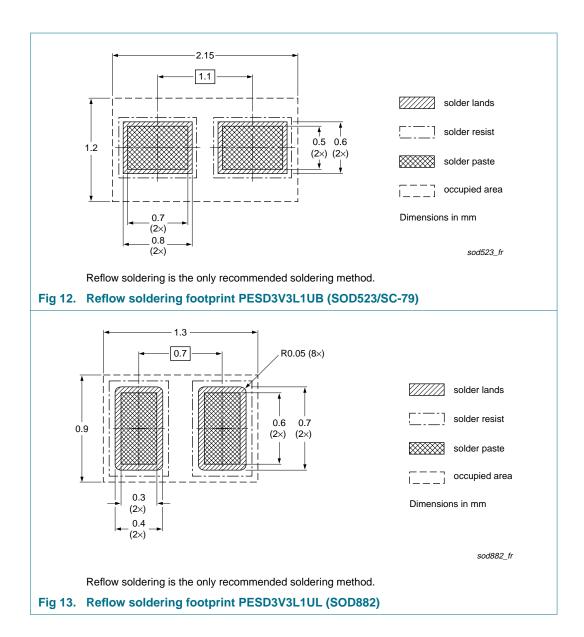
11. Soldering



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Low capacitance unidirectional ESD protection diodes

12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD3V3L1UA_UB_UL_1	20090617	Product data sheet	-	-

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 Product data sheet
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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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14. Contact information

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